

IXTY26P10T

IXTY26P10T Information





Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXTY26P10T Specifications

Manufacturer Part Number	IXTY26P10T
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-252-3, DPak (2 Leads + Tab), SC-63
Series	TrenchP?
FET Type	P-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	26A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10 V
Vgs(th) (Max) @ Id	4.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	52nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	3820pF @ 25V
Vgs (Max)	±15V
FET Feature	-
Power Dissipation (Max)	150W (Tc)
Rds On (Max) @ Id, Vgs	90 mOhm @ 13A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-252
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
	Report errors?

IXTY26P10T Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXTY26P10T Payment Methods



IXTY26P10T Shipping Methods



If you have any question about IXTY26P10T, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com